1. General description

NPN/PNP general-purpose transistors in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- · General-purpose transistor
- · High current
- · Reduces component count on Printed-Circuit Board (PCB)
- · Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- General-purpose switching and amplification
- Complementary driver
- · Half-bridge and full-bridge driver

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TR1 (NPN)						
V_{CEO}	collector-emitter voltage	open base	-	-	40	V
h _{FE}	DC current gain	V_{CE} = 10 V; I_{C} = 150 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02 ; T_{amb} = 25 °C	100	-	300	
TR2 (PNP)						<u> </u>
V_{CEO}	collector-emitter voltage	open base	-	-	-60	V
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -150 mA; pulsed; $t_{p} \le$ 300 μs; $\delta \le 0.02$; T_{amb} = 25 °C	100	-	300	
Per transis	stor; for the PNP transist	tor with negative polarity				,
I _C	collector current		-	-	600	mA



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B1	base TR1	<u> </u>	C1 E1 C2
2	E2	emitter TR2		
3	B2	base TR2	<u>0</u> <u>1 1 2 1</u> 3	TR1 TR2
4	C2	collector TR2	TSOP6 (SOT457)	
5	E1	emitter TR1		D4 50 00
6	C1	collector TR1		B1 E2 B2 aaa-022995

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
NMB2227A	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457		

7. Marking

Table 4. Marking codes

Type number	Marking code
NMB2227A	3B

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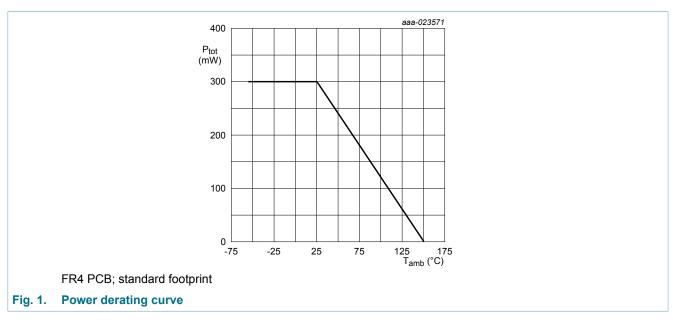
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
TR1 (NPN)	'					
V _{CBO}	collector-base voltage	open emitter		-	75	V
V _{CEO}	collector-emitter voltage	open base		-	40	V
TR2 (PNP)			·			
V _{CBO}	collector-base voltage	open emitter		-	-60	V
V _{CEO}	collector-emitter voltage	open base		-	-60	V
Per transist	or; for the PNP transistor wit	h negative polarity	·			
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	600	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	800	mA
I _{BM}	peak base current			-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



NMB2227A

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device					,	,	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

40 V, 600 mA NPN/PNP general-purpose transistors

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
TR1 (NPN)						
I _{CBO}	collector-base cut-off	V _{CB} = 60 V; I _E = 0 A; T _{amb} = 25 °C	-	-	10	nA
	current	V _{CB} = 60 V; I _E = 0 A; T _j = 125 °C	-	-	10	μA
I _{EBO}	emitter-base cut-off current	V_{EB} = 5 V; I_C = 0 A; T_{amb} = 25 °C	-	-	10	nA
h _{FE}	DC current gain	V_{CE} = 10 V; I_{C} = 1 mA; T_{amb} = 25 °C	50	-	-	
		V _{CE} = 10 V; I _C = 10 mA; T _{amb} = 25 °C	75	-	-	
		V_{CE} = 10 V; I_{C} = 150 mA; pulsed; $t_{p} \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	100	-	300	
		V_{CE} = 10 V; I_{C} = 500 mA; pulsed; $t_{p} \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 150 mA; I_B = 15 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	-	-	300	mV
		I_C = 500 mA; I_B = 50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02 ; T_{amb} = 25 °C	-	-	1	V
V_{BEsat}	base-emitter saturation voltage	I_C = 150 mA; I_B = 15 mA; pulsed; $t_p \le$ 300 μs; $δ \le 0.02$; T_{amb} = 25 °C	0.6	-	1.2	V
		I_C = 500 mA; I_B = 50 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	-	-	2	V
t _d	delay time	I _C = 150 mA; I _{Bon} = 15 mA;	-	-	15	ns
t _r	rise time	$I_{Boff} = -15 \text{ mA}; V_{CC} = 10 \text{ V};$ $T_{amb} = 25 ^{\circ}\text{C}$	-	-	20	ns
t _{on}	turn-on time	· and	-	-	35	ns
t _s	storage time		-	-	200	ns
t _f	fall time		-	-	60	ns
t _{off}	turn-off time		-	-	250	ns
C _C	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	8	pF
C _E	emitter capacitance	V_{EB} = 500 mV; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	25	pF
f _T	transition frequency	V_{CE} = 20 V; I_{C} = 20 mA; f = 100 MHz; T_{amb} = 25 °C	300	-	-	MHz
TR2 (PNP)						
I _{CBO}	collector-base cut-off	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-10	nA
	current	V_{CB} = -50 V; I_{E} = 0 A; T_{j} = 125 °C	-	-	-10	μA
I _{EBO}	emitter-base cut-off current	V_{EB} = -5 V; I_{C} = 0 A; T_{amb} = 25 °C	-	-	-50	nA
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -0.1 mA; T_{amb} = 25 °C	75	-	-	
		V_{CE} = -10 V; I_{C} = -1 mA; T_{amb} = 25 °C	100	-	-	
		V _{CE} = -10 V; I _C = -10 mA; T _{amb} = 25 °C	100	-	-	

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V_{CE} = -10 V; I_{C} = -150 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02 ; T_{amb} = 25 °C	100	-	300	
		V_{CE} = -10 V; I_{C} = -500 mA; pulsed; $t_{p} \le$ 300 μ s; $\delta \le 0.02$; T_{amb} = 25 °C	50	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -150 mA; I_B = -15 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	-	-	-400	mV
		I_C = -500 mA; I_B = -50 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	-	-	-1.6	V
V _{BEsat}	base-emitter saturation voltage	I_C = -150 mA; I_B = -15 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	-	-	-1.3	V
		I_C = -500 mA; I_B = -50 mA; pulsed; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T_{amb} = 25 °C	-	-	-2.6	V
t _d	delay time	I _C = -150 mA; I _{Bon} = -15 mA;	-	-	12	ns
t _r	rise time	$_{\text{Boff}}$ = 15 mA; V_{CC} = -10 V; V_{amb} = 25 °C	-	-	30	ns
t _{on}	turn-on time	· and	-	-	40	ns
t _s	storage time		-	-	300	ns
t _f	fall time		-	-	65	ns
t _{off}	turn-off time		-	-	365	ns
C _C	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	8	pF
C _E	emitter capacitance	V_{EB} = -2 V; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	-	30	pF
f _T	transition frequency	V_{CE} = -20 V; I_{C} = -50 mA; f = 100 MHz; T_{amb} = 25 °C	200	-	-	MHz

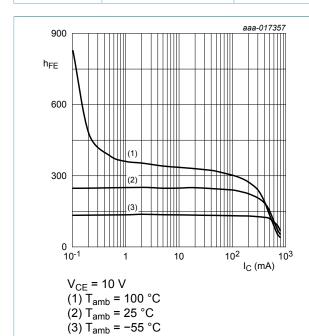


Fig. 2. NPN transistor: DC current gain as a function of collector current; typical values

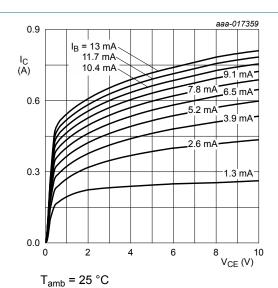
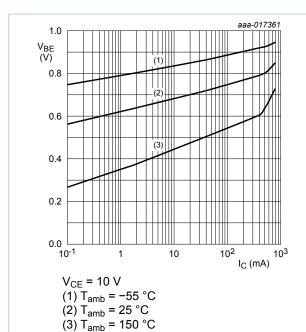
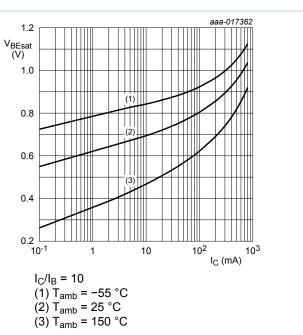


Fig. 3. NPN transistor: Collector current as a function of collector-emitter voltage; typical values

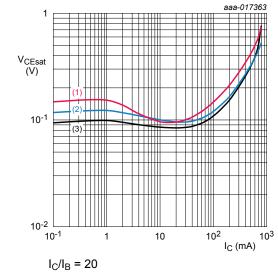
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NPN transistor: Base-emitter voltage as a Fig. 4. function of collector current; typical values



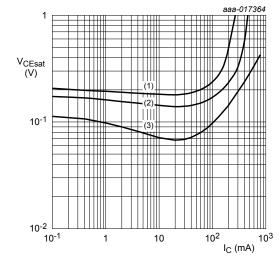
NPN transistor: Base-emitter saturation voltage Fig. 5. as a function of collector current; typical values



(1) T_{amb} = 150 °C

(2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

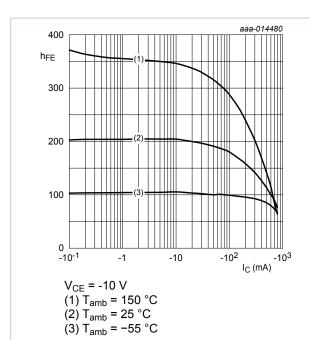
Fig. 6. **NPN** transistor: Collector-emitter saturation voltage as a function of collector current; typical values



 $T_{amb} = 25 \text{ °C}$ (1) $I_C/I_B = 100$ (2) $I_C/I_B = 50$ (3) $I_C/I_B = 10$

Fig. 7. **NPN** transistor: Collector-emitter saturation voltage as a function of collector current; typical values

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PNP transistor: DC current gain as a function Fig. 8. of collector current; typical values

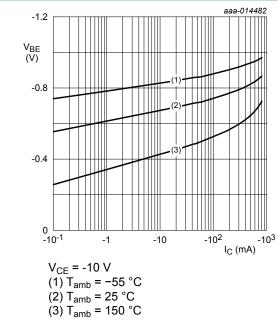
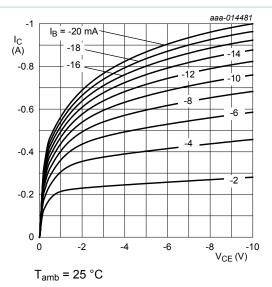
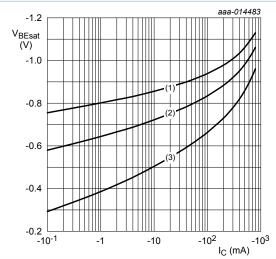


Fig. 10. PNP transistor: Base-emitter voltage as a function of collector current; typical values



PNP transistor: Collector current as a function Fig. 9. of collector-emitter voltage; typical values



 $I_C/I_B = 10$ (1) $T_{amb} = -55$ °C

(2) T_{amb} = 25 °C (3) T_{amb} = 150 °C

Fig. 11. PNP transistor: Base-emitter saturation voltage as a function of collector current; typical values

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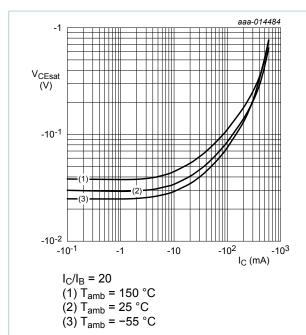


Fig. 12. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values

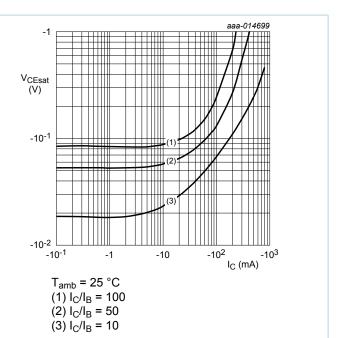


Fig. 13. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values

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11. Test information

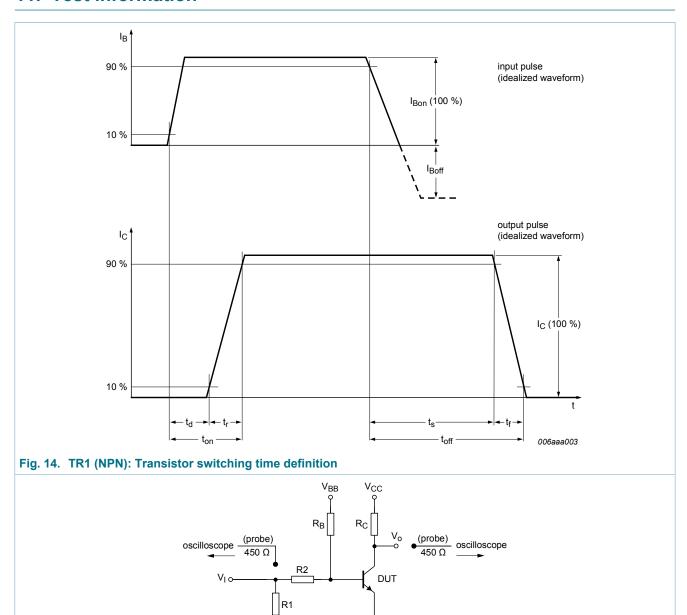
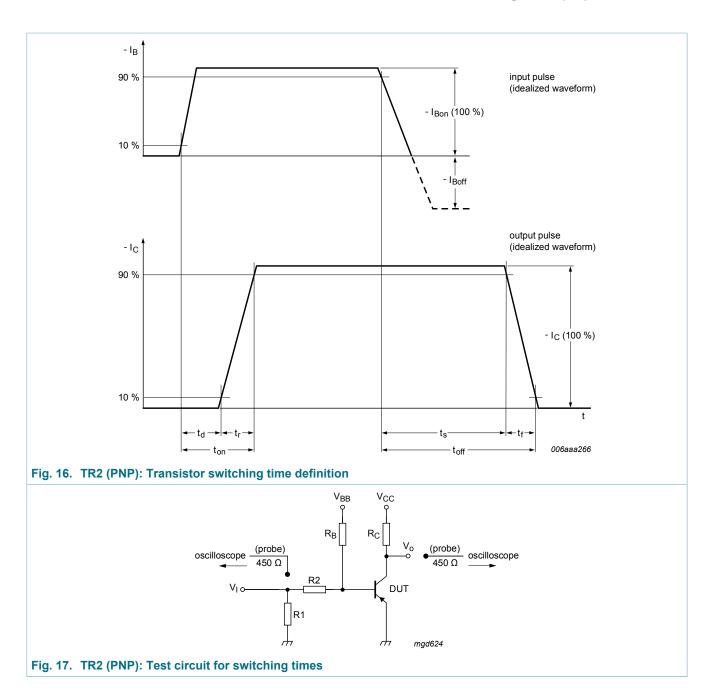


Fig. 15. TR1 (NPN): Test circuit for switching times

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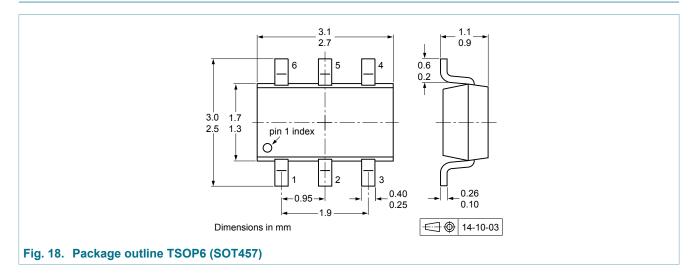


Quality information

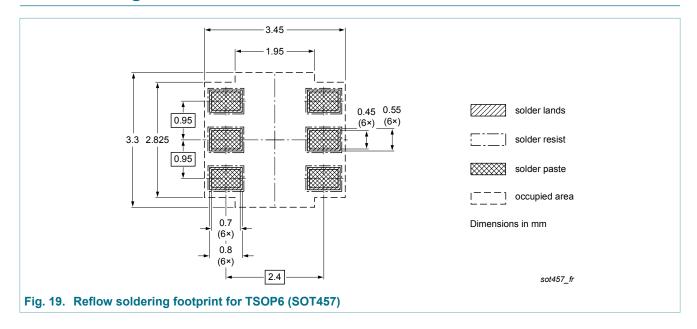
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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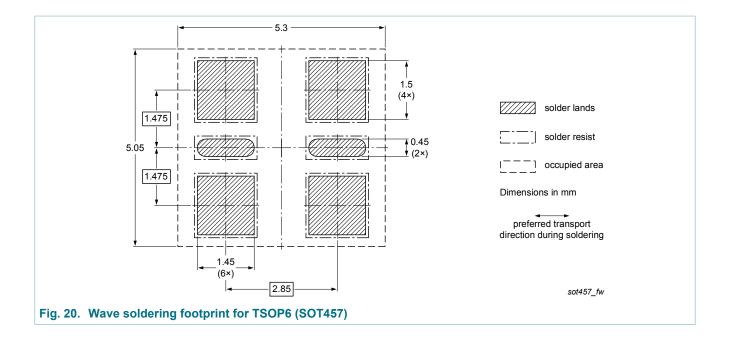
12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NMB2227A v.1	20160915	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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